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Kind regards,

Team Nexperia

PDTA114T series

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open Rev. 07 — 20 April 2007 Product data s

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family in small plastic packages.

Table 1. **Product overview**

| Type number | Package | Package | | | | |
|--------------|---------|---------|----------|-----------|--|--|
| | NXP | JEITA | JEDEC | | | |
| PDTA114TE | SOT416 | SC-75 | - | PDTC114TE | | |
| PDTA114TK | SOT346 | SC-59A | TO-236 | PDTC114TK | | |
| PDTA114TM | SOT883 | SC-101 | - | PDTC114TM | | |
| PDTA114TS[1] | SOT54 | SC-43A | TO-92 | PDTC114TS | | |
| PDTA114TT | SOT23 | - | TO-236AB | PDTC114TT | | |
| PDTA114TU | SOT323 | SC-70 | - | PDTC114TU | | |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Control of IC inputs

- Cost-saving alternative to BC857 series in digital applications
- Low current peripheral driver

1.4 Quick reference data

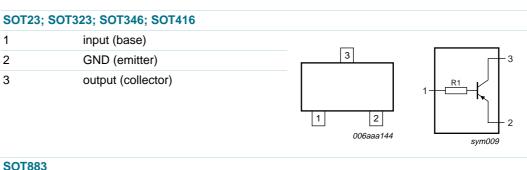
Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------|---------------------------|------------|-----|-----|------|-----------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -50 | V |
| Io | output current | | - | - | -100 | mA |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | $k\Omega$ |



2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** SOT54 1 input (base) output (collector) 3 GND (emitter) 006aaa217 SOT54A input (base) 2 output (collector) 3 GND (emitter) 001aab348 006aaa217 **SOT54** variant input (base) 2 output (collector) 3 GND (emitter) 001aab447 006aaa217



| | | 006aaa144 | sym009 |
|--------|--------------------|------------------------|--------|
| SOT883 | } | | |
| 1 | input (base) | | |
| 2 | GND (emitter) | 1 | 3 |
| 3 | output (collector) | 2 Transparent top view | R1 2 |
| | | | sym009 |

3. Ordering information

Table 4. Ordering information

| | 9 | | |
|--------------|---------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| PDTA114TE | SC-75 | plastic surface-mounted package; 3 leads | SOT416 |
| PDTA114TK | SC-59A | plastic surface-mounted package; 3 leads | SOT346 |
| PDTA114TM | SC-101 | leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm | SOT883 |
| PDTA114TS[1] | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |
| PDTA114TT | - | plastic surface-mounted package; 3 leads | SOT23 |
| PDTA114TU | SC-70 | plastic surface-mounted package; 3 leads | SOT323 |
| | | | |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5. Marking codes

| Table of Historia | |
|-------------------|-----------------------------|
| Type number | Marking code ^[1] |
| PDTA114TE | 11 |
| PDTA114TK | 23 |
| PDTA114TM | DE |
| PDTA114TS | TA114T |
| PDTA114TT | *11 |
| PDTA114TU | *23 |

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|---|--------------|------|------|
| V_{CBO} | collector-base voltage | open emitter | - | -50 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| lo | output current | | - | -100 | mA |
| I _{CM} | peak collector current | single pulse; $t_p \le 1 \text{ ms}$ | - | -100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 ^{\circ}C$ | | | |
| | PDTA114TE | | <u>[1]</u> _ | 150 | mW |
| | PDTA114TK | | <u>[1]</u> _ | 250 | mW |
| | PDTA114TM | | [2][3] | 250 | mW |
| | PDTA114TS | | <u>[1]</u> _ | 500 | mW |
| | PDTA114TT | | <u>[1]</u> - | 250 | mW |
| | PDTA114TU | | <u>[1]</u> _ | 200 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------|---|-------------|-------------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | | | | |
| | PDTA114TE | <u>]</u> | 1] _ | - | 833 | K/W |
| | PDTA114TK | <u>]</u> | 1] _ | - | 500 | K/W |
| | PDTA114TM | [2][| 3] _ | - | 500 | K/W |
| | PDTA114TS | <u>[</u> | 1] _ | - | 250 | K/W |
| | PDTA114TT | <u>[</u> | <u>1]</u> _ | - | 500 | K/W |
| | PDTA114TU | <u>]</u> | 1] _ | - | 625 | K/W |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

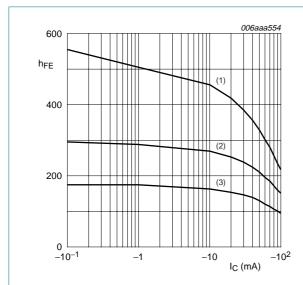
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

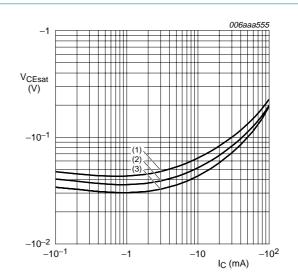
| anno | • | | | | | |
|--------------------|--------------------------------------|--|-----|-----|------------|-----------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| I_{CBO} | collector-base cut-off current | $V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$ | - | - | -100 | nA |
| I_{CEO} | collector-emitter | $V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$ | - | - | -1 | μΑ |
| | cut-off current | $V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$ | - | - | –50 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$ | - | - | -100 | nA |
| h _{FE} | DC current gain | $V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ mA}$ | 200 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -10 \text{ mA};$ $I_B = -0.5 \text{ mA}$ | - | - | -150 | mV |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | $k\Omega$ |
| C _c | collector capacitance | $V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz | - | - | 3 | pF |
| | | | | | | |





- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



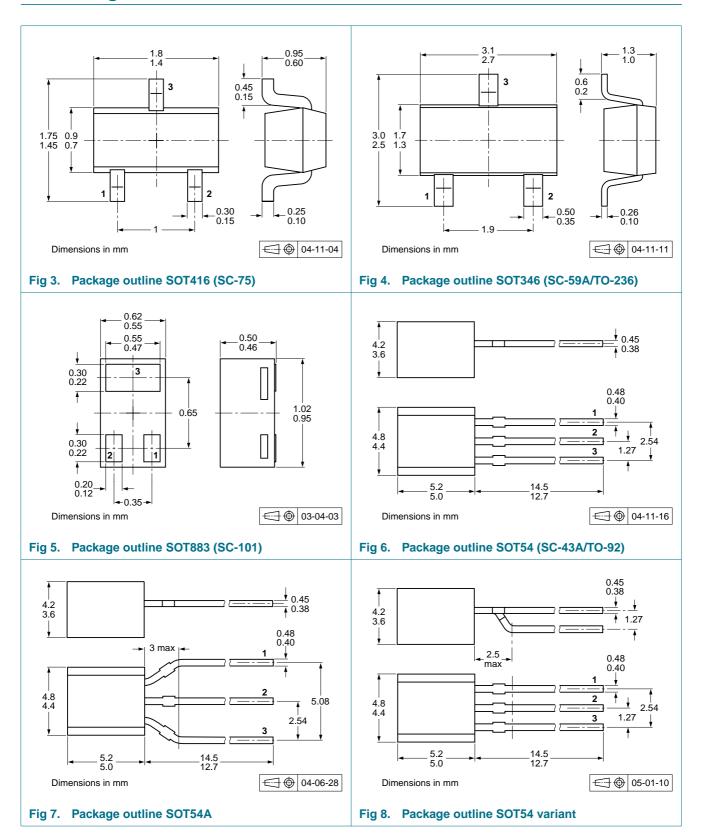
$$I_{\rm C}/I_{\rm B}=20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

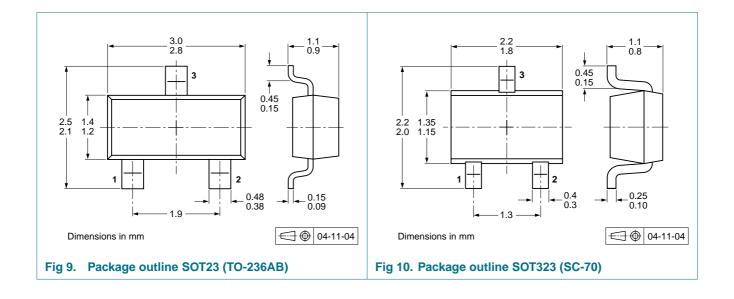
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8. Package outline



PDTA114T_SER_7

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9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packin | Packing quantity | | |
|-------------|---------------|--------------------------------|--------|------------------|-------|--|
| | | | 3000 | 5000 | 10000 | |
| PDTA114TE | SOT416 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA114TK | SOT346 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA114TM | SOT883 | 2 mm pitch, 8 mm tape and reel | - | - | -315 | |
| PDTA114TS | SOT54 | bulk, straight leads | - | -412 | - | |
| | SOT54A | tape and reel, wide pitch | - | - | -116 | |
| | | tape ammopack, wide pitch | - | - | -126 | |
| | SOT54 variant | bulk, delta pinning | - | -112 | - | |
| PDTA114TT | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | - | -235 | |
| PDTA114TU | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

| Document ID | Delegge deta | Date about status | Change netice | Cunarandan | | | |
|-------------------|---|------------------------------|---------------------|----------------------------|--|--|--|
| | Release date | Data sheet status | Change notice | Supersedes | | | |
| PDTA114T_SER_7 | 20070420 | Product data sheet | - | PDTA114T_SERIES_6 | | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | | |
| | Legal texts | have been adapted to the ne | ew company name whe | ere appropriate. | | | |
| | Type number | er PDTA114TEF removed | | | | | |
| | Section 1.2 | "Features": amended | | | | | |
| | Section 1.3 | "Applications": amended | | | | | |
| | • Table 4 "Or | dering information": added | | | | | |
| | Table 5 "Marking codes": enhanced table note section | | | | | | |
| | Table 6 "Limiting values": I _{CM} peak collector current conditions added | | | | | | |
| | • <u>Figure 1</u> , <u>2</u> , <u>7</u> and <u>8</u> : added | | | | | | |
| | • Figure 3, 4, 5, 6, 9 and 10: superseded by minimized package outline drawings | | | | | | |
| | Section 9 "F | Packing information": added | | | | | |
| | Section 11 | "Legal information": updated | | | | | |
| PDTA114T_SERIES_6 | 20040802 | Product specification | - | PDTA114T_SERIES_5 | | | |
| PDTA114T_SERIES_5 | 20030909 | Product specification | - | PDTA114T_SERIES_4 | | | |
| PDTA114T_SERIES_4 | 20030410 | Product specification | - | PDTA114TE_2 | | | |
| | | | | PDTA114TK_3 | | | |
| | | | | PDTA114TS_2 PDTA114TT_3 | | | |
| | | | | PDTA114T1_3 PDTA114TU_3 | | | |
| PDTA114TE_2 | 19980723 | Preliminary specification | - | PDTA114TE_1 | | | |
| PDTA114TK_3 | 19980515 | Product specification | - | PDTA114TK_2 | | | |
| PDTA114TS_2 | 19980515 | Product specification | - | PDTA114TS_1 | | | |
| | | Objective energification | | DDTA444TT 0 | | | |
| PDTA114TT_3 | 19990413 | Objective specification | - | PDTA114TT_2 | | | |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTA114T series

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

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